## NSN 5961-01-422-7398

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-422-7398 **Inclosure Material:** Metal **Overall Length:** 1.201 inches Overall Diameter: 0.424 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 54.0 nonrepetitive peak reverse voltage, peak total value and 45.0 working peak reverse voltage **Current Rating Per Characteristic:** 25.00 amperes source cutoff current absolute and 600.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Test Data Document:** 89954-342a9600 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:**